

UNISONIC TECHNOLOGIES CO., LTD

UK3019 **Power MOSFET**

2.5V DRIVE SILICON **N-CHANNEL MOSFET**

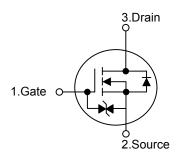
DESCRIPTION

The UTC UK3019 is a silicon N-channel MOSFET which has been designed to minimize on-state resistance while it provides rugged, reliable and fast switching performance. The product is particularly suited for low voltage, low current applications such as small servo motor controller, power MOSFET gate drivers, and other switching applications.

FEATURES

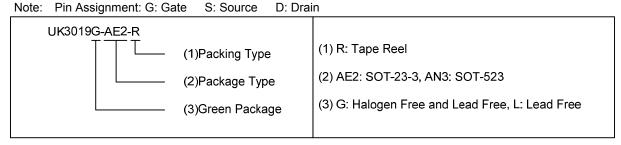
- * Min V_{DSS} =30V
- * $R_{DS(ON)} \le 8.0 \Omega$ @ $I_D=10mA$, $V_{GS}=4.0V$
- * $R_{DS(ON)} \le 13 \ \Omega$ @ $I_D=1mA$, $V_{GS}=2.5V$
- * Pulsed ID=400mA
- * Low Voltage Drive (2.5V)

SYMBOL

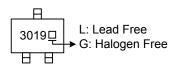


ORDERING INFORMATION

Ordering Number		Doolsons	Pin Assignment			Daakina	
Lead Free	Halogen Free	Package	1	2	3	Packing	
UK3019L-AE2-R	UK3019G-AE2-R	SOT-23-3	G	S	D	Tape Reel	
UK3019L-AN3-R	UK3019G-AN3-R	SOT-523	G	S	D	Tape Reel	



MARKING



SOT-23-3 (JEDEC TO-236) SOT-523

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■ ABSOLUTE MAXIMUM RATING (T_A=25°C, unless otherwise specified)

PARAMETER		SYMBOL	RATINGS	UNIT
Drain-Source Voltage		$V_{ extsf{DSS}}$	30	V
Gate-Source Voltage		V_{GSS}	±20	V
Drain Current	Continuous	I_D	100	mA
	Pulsed (Note 2)	I _{DP}	400	mA
Power Dissipation (Note 3)	SOT-23-3	P _D	200	mW
	SOT-523		150	mW
Junction Temperature		T_J	+150	°C
Storage Temperature		T_{STG}	-55 ~ +150	°C

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

- 2. Pw≤10µs, Duty cycle≤50%
- 3. With each pin mounted on the recommended lands.

■ THERMAL CHARACTERISTICS

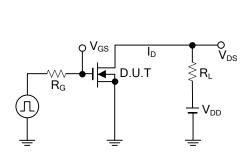
PARAMETER		SYMBOL	BOL RATINGS	
Junction to Ambient	SOT-23-3	0	625	°C/W
so	SOT-523	θ_{JA}	833	°C/W

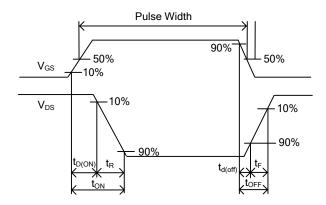
■ **ELECTRICAL CHARACTERISTICS** (T_A=25°C, unless otherwise specified)

SYMBOL	TEST CONDITIONS		TYP	MAX	UNIT			
OFF CHARACTERISTICS								
BV _{DSS}	V_{GS} =0V, I_D =10 μ A	30			V			
I _{DSS}	V_{DS} =30V, V_{GS} =0V			1	μΑ			
I _{GSS}	V_{DS} =0V, V_{GS} =±20V			±1	μA			
ON CHARACTERISTICS								
$V_{GS(TH)}$	V_{DS} =3 V , I_D =100 μ A	0.8		1.5	V			
	I _D =10mA, V _{GS} =4.0V		5.0	8.0	Ω			
KDS(ON)	I _D =1mA, V _{GS} =2.5V		7.0	13	Ω			
			ā.					
C _{ISS}			13		pF			
Coss	V_{DS} =5V, V_{GS} =0V, f = 1MHz		9		pF			
C _{RSS}			4		pF			
t _{D(ON)}			15		ns			
t _R	V _{GS} =5V, V _{DD} ≈5V		35		ns			
t _{D(OFF)}	I_D =10mA, R_L =500 Ω , R_G =10 Ω		80		ns			
t _F			80		ns			
	$\begin{array}{c} BV_{DSS} \\ I_{DSS} \\ I_{GSS} \\ \\ V_{GS(TH)} \\ R_{DS(ON)} \\ \\ \\ C_{ISS} \\ C_{OSS} \\ C_{RSS} \\ \\ \\ t_{D(ON)} \\ \\ \\ t_{R} \\ \\ \\ \\ t_{D(OFF)} \end{array}$	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$			

UK3019 Power MOSFET

■ TEST CIRCUITS AND WAVEFORMS





Switching Time Measurement Circuit

Switching Time Waveforms

UTC assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all UTC products described or contained herein. UTC products are not designed for use in life support appliances, devices or systems where malfunction of these products can be reasonably expected to result in personal injury. Reproduction in whole or in part is prohibited without the prior written consent of the copyright owner. UTC reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.